





# - 0

#### **Features**

- ♦ Glass passivated chip junction
- ♦ High efficiency, Low VF
- ♦ High current capability
- ♦ High reliability
- ♦ High surge current capability
- ♦ Low power loss
- Green compound with suffix "G" on packing code & prefix "G" on datecode

### **Mechanical Data**

- ♦ Cases: TO-220AC Molded plastic
- → Epoxy: UL 94V-0 rate flame retardant
- Lead: Pure tin plated, lead free, solderable per MIL-STD-202, Method 208 guaranteed
- Polarity: As marked
- ♦ High temperature soldering guaranteed: 260°C/10 seconds .16", (4.06mm) from case.
- ♦ Weight: 2.24 grams

#### 

063(1.6) Max.

.577(14.79) .514(13.19)

**TO-220AC** 

PIN 1 O CASE

.205(5.20)

#### **Dimensions in inches and (millimeters)**

# **Marking Diagram**

GPA160X = Specific Device Code
G = Green Compound

**GPA1601 - GPA1607** 

.109(2.8)

.025(0.64)

16.0 AMPS. Glass Passivated Rectifiers

Y = Year WW = Work Week



.037(0.94)

# **Maximum Ratings and Electrical Characteristics**

Rating at 25  $^{\circ}\mathrm{C}$  ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

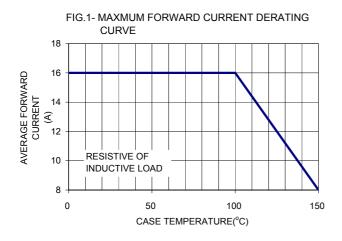
Type Number	Symbol	GPA 1601	GPA 1602	GPA 1603	GPA 1604	GPA 1605	GPA 1606	GPA 1607	Units
Maximum Recurrent Peak Reverse Voltage	$V_{RRM}$	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	$V_{RMS}$	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	$V_{DC}$	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified	I <sub>F(AV)</sub>	16							Α
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I <sub>FSM</sub>	250							Α
Maximum Instantaneous Forward Voltage (Note 1) @ 16 A	V <sub>F</sub>	1.1						V	
Maximum DC Reverse Current at  @ T <sub>A</sub> =25 ℃		10							uA
Rated DC Blocking Voltage @ T <sub>A</sub> =125℃	I <sub>R</sub>	250							
Typical Junction Capacitance (Note 2)	Cj	100						pF	
Typical Thermal Resistance	$R_{\theta JC}$	2.0						°C/W	
Operating Temperature Range	T <sub>J</sub>	- 65 to + 150						οС	
Storage Temperature Range	T <sub>STG</sub>	- 65 to + 150						οС	

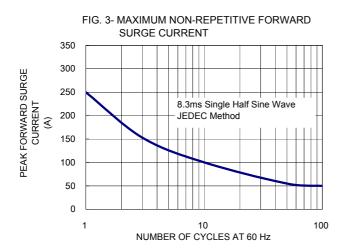
Note1: Pulse Test with PW=300 usec, 1% Duty Cycle

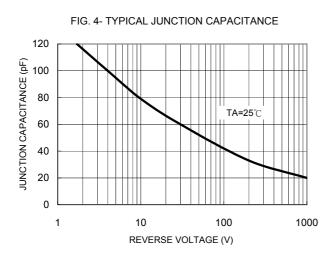
Note2: Measured at 1 MHz and Applied Reverse Voltage of 4.0 Volts D.C.

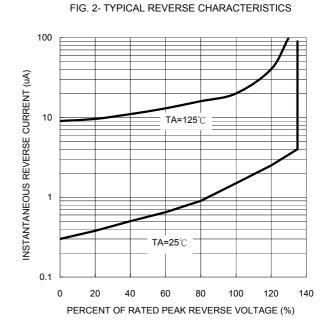


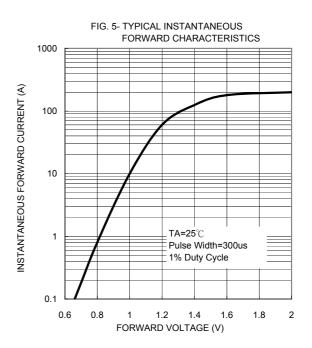
# RATINGS AND CHARACTERISTIC CURVES (GPA1601 THRU GPA1607)











Version:E11